

RoHS Compliant



Features:

- · Glass passivated chip junction
- High efficiency, low V_F
- High current capability
- High reliability
- High surge current capability
- Low power loss

Specifications:

Mechanical Data:

Cases : Moulded plastic

Lead : Pure tin plated, lead free, solderable per MIL-STD-202, Method 208 guaranteed

Polarity : Colour band denotes cathode end

High temperature soldering guaranteed : 260°C/10 seconds/0.375", (9.5mm) lead lengths at 5lbs., (2.3kg) tension

Weight : 0.34g

Epoxy : UL 94V-0 rate flame retardant

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

Type Number	Symbol	FR103G	FR105G	FR107G	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	200	600	1,000	
Maximum RMS Voltage	V _{RMS}	140	420	700	V
Maximum DC Blocking Voltage	V _{DC}	200	600	1,000	
Maximum Average Forward Rectified Current 0.375" (9.5mm) Lead Length at T _A = 55°C	l(AV)	1			. А
Peak Forward Surge Current, 8.3ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I _{FSM}	30			
Maximum Instantaneous Forward Voltage at 1A	V _F	1.3		V	





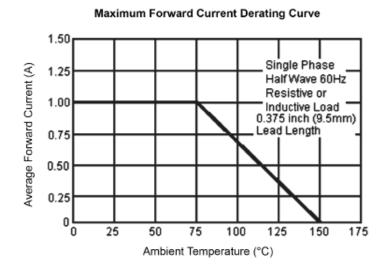
Type Number	Symbol	FR103G	FR105G	FR107G	Units
Maximum DC Reverse Current at $T_A = 25^{\circ}C$ at Rated DC Blocking Voltage at $T_A = 125^{\circ}C$	I _R		5 150		μA μA
Maximum Reverse Recovery Time (Note 1)	T _{rr}	150	250	500	nS
Typical Junction Capacitance (Note 2)	C _j	10			pF
Typical Thermal Resistance	$R_{\theta JA}$	70			°C/W
Operating Temperature Range	T _J	-65 to +150			°C
Storage Temperature Range	T _{STG}				

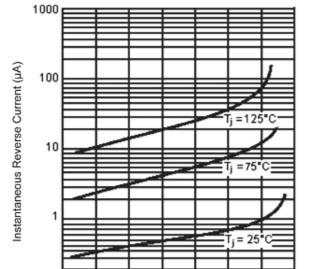
Note: 1. Reverse Recovery Test Conditions: $I_F = 0.5A$, $I_R = 1A$, $I_{RR} = 0.25A$.

Note: 2. Measured at 1MHz and Applied Reverse Voltage of 4V DC.

Note: 3. Mount on Cu-Pad Size 5mm x 5mm on PCB.

Ratings and Characteristic Curves (FR103G, FR105G, FR107G)





Typical Reverse Characteristics Per Leg

60 Percent of Rated Peak Reverse Voltage (%)

0.1

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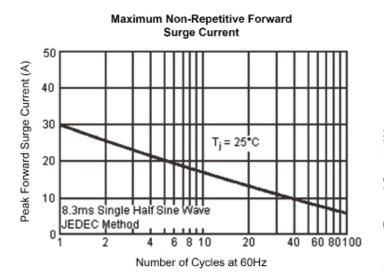


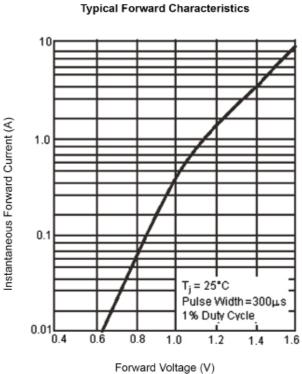
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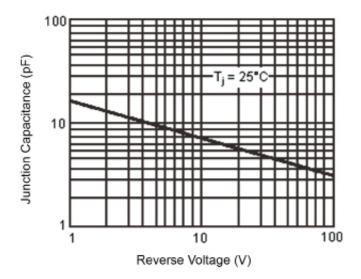
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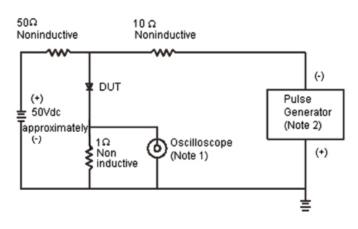


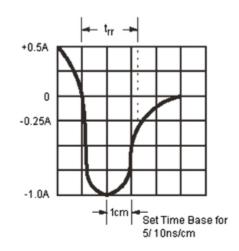
Typical Junction Capacitance



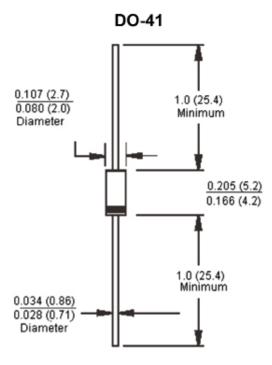


Reverse Recovery Time Characteristic and Test Circuit Diagram





Note: 1. Rise Time = 7ns Maximum. Input Impedance = $1M\Omega$ 22pf **Note:** 2. Rise Time = 10ns Maximum Source Impedance = 50Ω



Dimensions: Inches (Millimetres)

Part Number Table

Description	Part Number		
Diode, Fast, 1A, 200V	FR103G		
Diode, Fast, 1A, 600V	FR105G		
Diode, Fast, 1A, 1,000V	FR107G		

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